



**SBR3U40P1** 

# 3.0A SBR<sup>®</sup> SUPER BARRIER RECTIFIER POWERDI<sup>®</sup>

#### **Features**

- Ultra Low Forward Voltage Drop
- Superior Reverse Avalanche Capability
- Patented Interlocking Clip Design for High Surge Current Capacity
- Patented Super Barrier Rectifier Technology
- Soft, Fast Switching Capability
- 150°C Operating Junction Temperature
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### Mechanical Data

- Case: POWERDI123
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Polarity Indicator: Cathode Band
- Weight: 0.018 grams (approximate)

#### POWERDI123



Top View

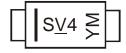
## **Ordering Information** (Note 4)

Part Number	Case	Packaging
SBR3U40P1-7	POWERDI123	3000/Tape & Reel
SBR3U40P1Q-7	POWERDI123	3000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

## **Marking Information**



SV4 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: U = 2007) M = Month (ex: 9 = September)

Date Code Key

Year	2007	2008	2009	2010	201	1 20	)12	2013	2014	2015	2016	2017
Code	U	V	W	X	Υ		Z	Α	В	С	D	E
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>RM</sub>	40	٧
RMS Reverse Voltage	V <sub>R(RMS)</sub>	28	V
Average Rectified Output Current (See Figure 1)	lo	3	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	75	Α

## Thermal Characteristics

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance Thermal Resistance Junction to Soldering (Note 5) Thermal Resistance Junction to Ambient (Note 6) Thermal Resistance Junction to Ambient (Note 7)	$egin{array}{c} R_{ heta} J S & & & & & & & & & & & & & & & & & &$	5 175 100	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

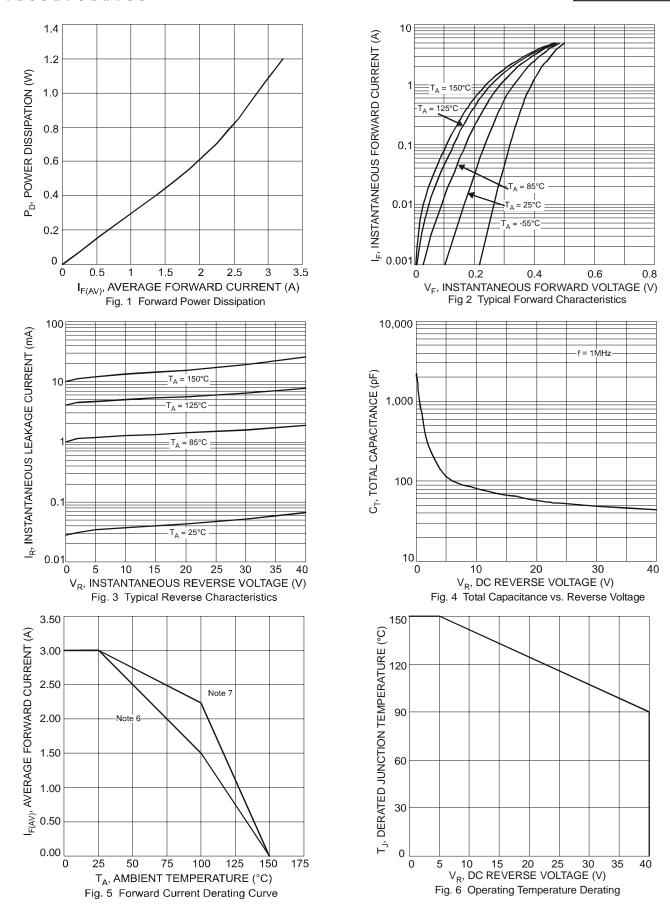
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 8)	$V_{(BR)R}$	40	ı	-	V	$I_R = 400 \mu A$
Forward Voltage Drop	V <sub>F</sub>	-	0.30	0.34	V	I <sub>F</sub> = 0.5A, T <sub>J</sub> = +25°C
		-	0.34	0.39		$I_F = 1.0A, T_J = +25^{\circ}C$
		-	0.42	0.47		$I_F = 3.0A, T_J = +25^{\circ}C$
Lookogo Current (Note 9)	I <sub>R</sub>	-	70	400	μΑ	$V_R = 40V, T_J = +25^{\circ}C$
Leakage Current (Note 8)		-	8	40	mA	$V_R = 40V, T_J = +125$ °C

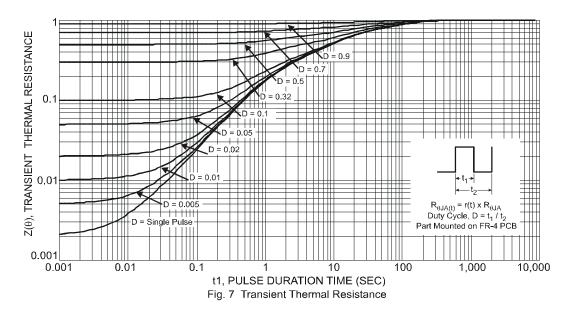
Notes:

- Theoretical R<sub>BJS</sub> calculated from the top center of the die straight down to the PCB cathode tab solder junction.
   FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com.
   Polymide PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com.
   Short duration pulse test used to minimize self-heating effect.



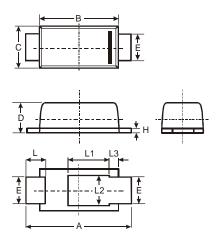






# **Package Outline Dimensions**

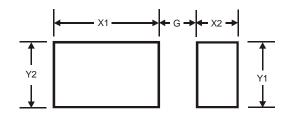
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



F	POWERDI123							
Dim	Min	Max	Тур					
Α	3.50	3.90	3.70					
В	2.60	3.00	2.80					
С	1.63	1.93	1.78					
D	0.93	1.00	0.98					
Е	0.85	1.25	1.00					
Н	0.15	0.25	0.20					
L	0.40	0.50	0.45					
L1	-	-	1.35					
L2	-	-	1.10					
L3	-	-	0.20					
All D	All Dimensions in mm							

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
G	1.0
X1	2.2
X2	0.9
Y1	1.4
Y2	1.4



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